
HD74BC620A

Octal Bus Transceivers With 3 State Outputs

HITACHI

ADE-205-024 (Z)

Rev. 0

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Description

The HD74BC620A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC. When the frequency is 10 MHz. The device has eight bus transceivers with three state outputs in a 20 pin package. This device allows data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic levels at the enable inputs ($\overline{\text{GBA}}$ and GAB). The enable inputs can be used to disable the device so that the buses are effectively isolated.

Features

- Input/Output are at high impedance state when power supply is off.
- Input pins can be open, when not used, owing to built in input pull up circuit.
- Input is TTL level.
- Wide operating temperature range

Ta = -40 to +85°C.

Function Table

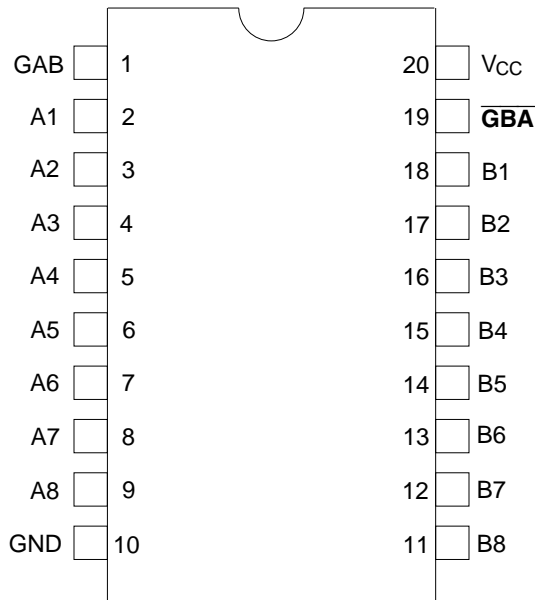
Enable Inputs

| $\overline{\text{GBA}}$ | GAB | Operation |
|-------------------------|-----|--|
| L | L | $\overline{\text{B}}$ data to A bus |
| H | H | $\overline{\text{A}}$ data to B bus |
| H | L | Isolation |
| L | H | $\overline{\text{B}}$ data to A bus $\overline{\text{A}}$ data to B bus |

H : High level

L : Low level

Pin Arrangement



(Top view)

Absolute Maximum Ratings

| Item | Symbol | Rating | Unit |
|--------------------------|-----------------------|--------------|------|
| Supply voltage | V _{CC} | -0.5 to +7.0 | V |
| Input diode current | I _{IK} | ±30 | mA |
| Input voltage | V _{IN} | -0.5 to +7.5 | V |
| Output voltage | V _{OUT} | -0.5 to +7.5 | V |
| Off state output voltage | V _{OUT(off)} | -0.5 to +5.5 | V |
| Storage temperature | T _{stg} | -65 to +150 | °C |

Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

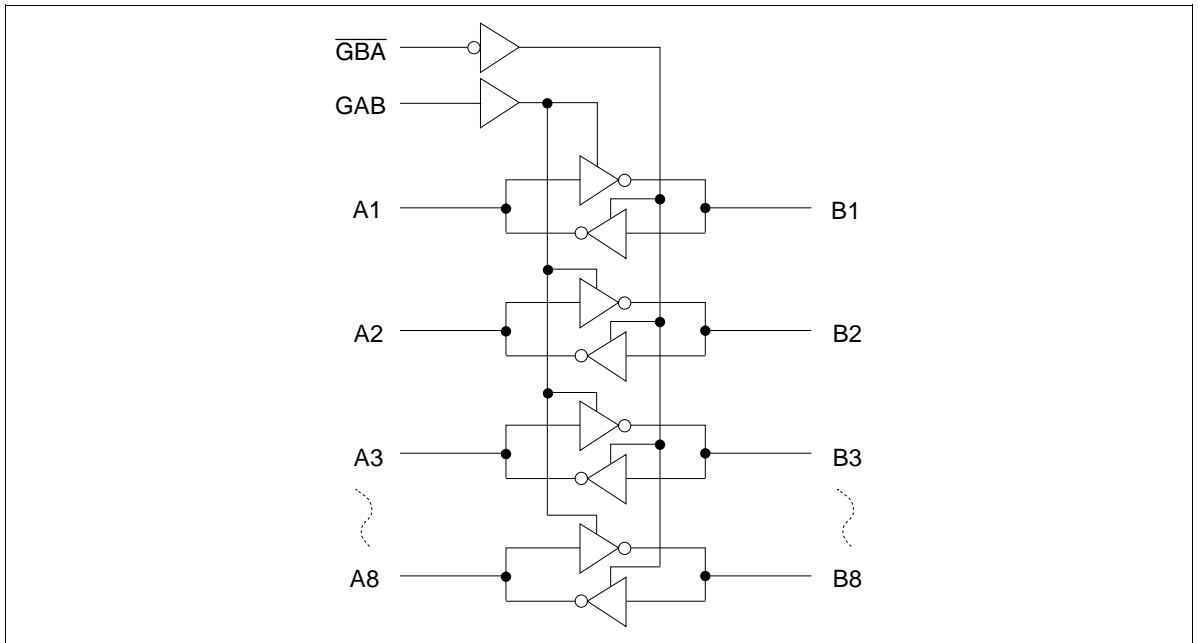
Recommended Operating Conditions

| Item | Symbol | Min | Typ | Max | Unit |
|------------------------|------------|-----|-----|----------|------|
| Supply voltage | V_{CC} | 4.5 | 5.0 | 5.5 | V |
| Input voltage | V_{IN} | 0 | — | V_{CC} | V |
| Ouput voltage | V_{OUT} | 0 | — | V_{CC} | V |
| Operating temperature | Topr | -40 | — | 85 | °C |
| Input rise/fall time*1 | t_r, t_f | 0 | — | 8 | ns/V |

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Logic Diagram



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Electrical Characteristics (Ta = -40 to +85°C)

| Item | Symbol | V _{cc} (V) | Min | Max | Unit | Test Conditions |
|--|---------------------------------|---------------------|------|------|------|--|
| Input voltage | V _{IH} | | 2.0 | — | V | |
| | V _{IL} | | — | 0.8 | V | |
| Output voltage | V _{OH} | 4.5 | 2.4 | — | V | I _{OH} = -3 mA |
| | | 4.5 | 2.0 | — | V | I _{OH} = -15 mA |
| | V _{OL} | 4.5 | — | 0.5 | V | I _{OL} = 48 mA |
| | | 4.5 | — | 0.55 | V | I _{OL} = 64 mA |
| Input diode voltage | V _{IK} | 4.5 | — | -1.2 | V | I _{IN} = -18 mA |
| Input current | I _I | 5.5 | — | -250 | μA | V _{IN} = 0 V |
| | | 5.5 | — | 1.0 | μA | GAB or $\overline{\text{GBA}}$, V _{IN} = 5.5 V |
| | | 5.5 | — | 100 | μA | An or Bn, V _{IN} = 5.5 V |
| | | 5.5 | — | 100 | μA | GAB or $\overline{\text{GBA}}$ = 7 V |
| Output short circuit current* ¹ | I _{OS} | 5.5 | -100 | -225 | mA | V _{IN} = 0 or 5.5 V |
| Off state output current | I _{OZH} | 5.5 | — | -100 | μA | V _O = 2.7 V |
| | I _{OZL} | 5.5 | — | -250 | μA | V _O = 0.5 V |
| Supply current | I _{CCL} | 5.5 | — | 29.5 | mA | V _{IN} = 0 or 5.5 V All outputs is "L" |
| | I _{CCH} | 5.5 | — | 2.5 | mA | V _{IN} = 0 or 5.5 V All outputs is "H" |
| | I _{CCZ} | 5.5 | — | 4.5 | mA | V _{IN} = 0 or 5.5 V All outputs is "Z" |
| | I _{CCT} * ² | 5.5 | — | 1.5 | mA | V _{IN} = 3.4 or 0.5 V |

Notes: 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

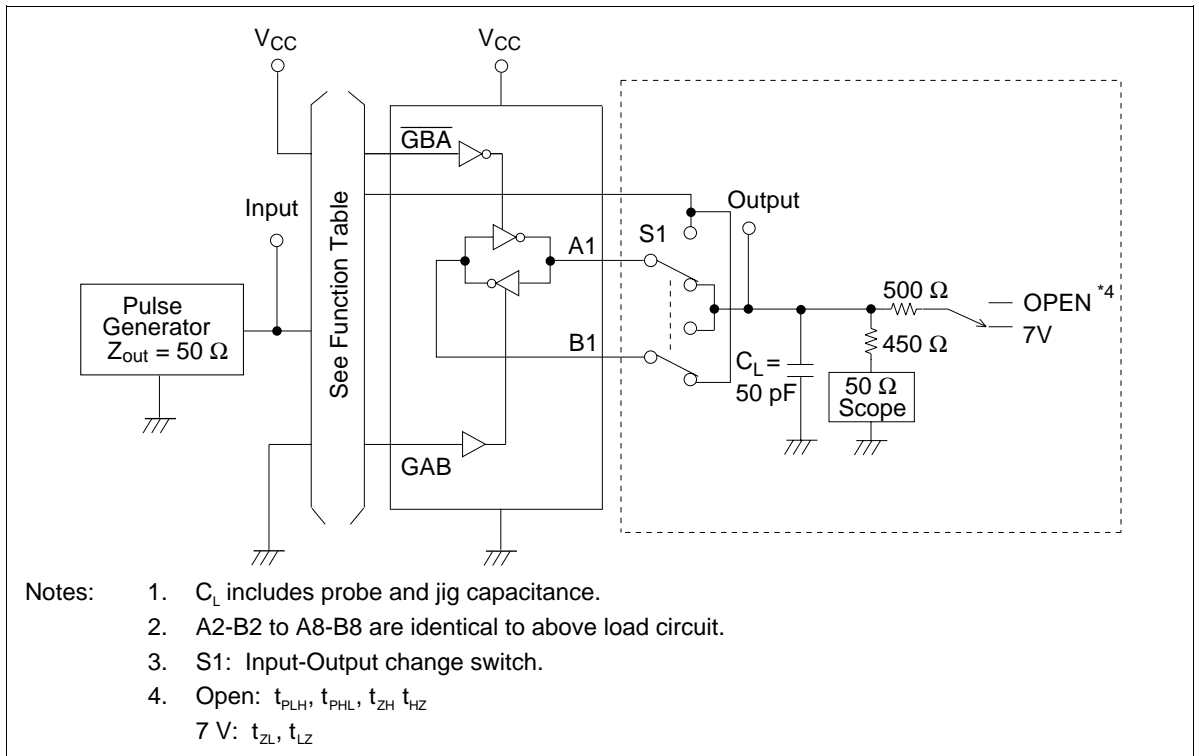
2. When input by the TTL level, it shows I_{cc} increase at per one input pin.

Switching Characteristics ($C_L = 50 \text{ pF}$)

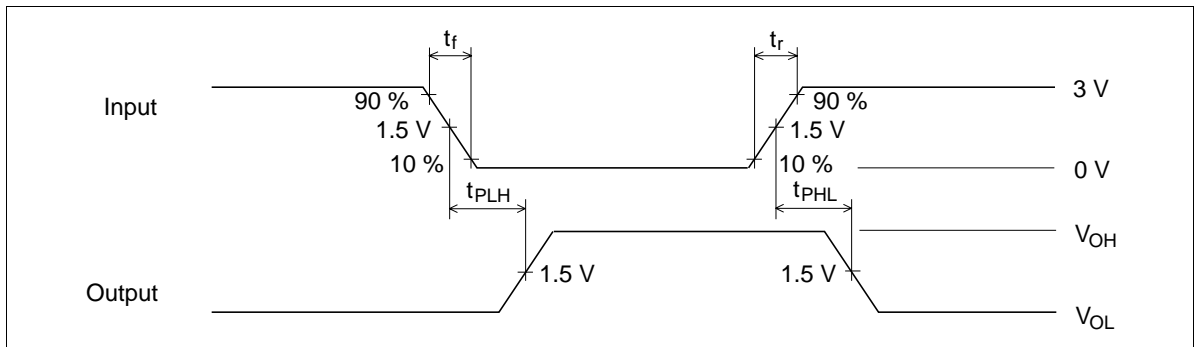
| Item | Symbol | $T_a = 25^\circ\text{C}$ $V_{CC} = 5.0 \text{ V}$ | | $T_a = -40 \text{ to } +85^\circ\text{C}$ $V_{CC} = 5.0 \text{ V} \pm 10\%$ | | Unit | Test Conditions |
|------------------------|-----------|--|-----|--|------|------|--------------------------------------|
| | | Min | Max | Min | Max | | |
| Propagation delay time | t_{PLH} | 3.0 | 6.0 | 3.0 | 7.0 | ns | An to Bn |
| | t_{PHL} | 3.0 | 6.0 | 3.0 | 7.0 | | |
| | t_{PLH} | 3.0 | 6.0 | 3.0 | 7.0 | ns | Bn to An |
| | t_{PHL} | 3.0 | 6.0 | 3.0 | 7.0 | | |
| Output enable time | t_{ZH} | 3.0 | 9.0 | 3.0 | 11.0 | ns | GAB to Bn |
| | t_{ZL} | 3.0 | 9.0 | 3.0 | 11.0 | | |
| | t_{ZH} | 3.0 | 9.0 | 3.0 | 11.0 | ns | $\overline{\text{G}}\text{BA to An}$ |
| | t_{ZL} | 3.0 | 9.0 | 3.0 | 11.0 | | |
| Output disable time | t_{HZ} | 3.0 | 8.0 | 3.0 | 10.0 | ns | GAB to Bn |
| | t_{LZ} | 3.0 | 8.0 | 3.0 | 10.0 | | |
| | t_{HZ} | 3.0 | 8.0 | 3.0 | 10.0 | ns | $\overline{\text{G}}\text{BA to An}$ |
| | t_{LZ} | 3.0 | 8.0 | 3.0 | 10.0 | | |
| Input capacitance | C_{IN} | 3.0 (Typ) | | — | | pF | $V_{IN} = V_{CC} \text{ or GND}$ |
| Output capacitance | C_{IO} | 15.0 (Typ) | | — | | pF | $V_{IO} = V_{CC} \text{ or GND}$ |

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Test Circuit

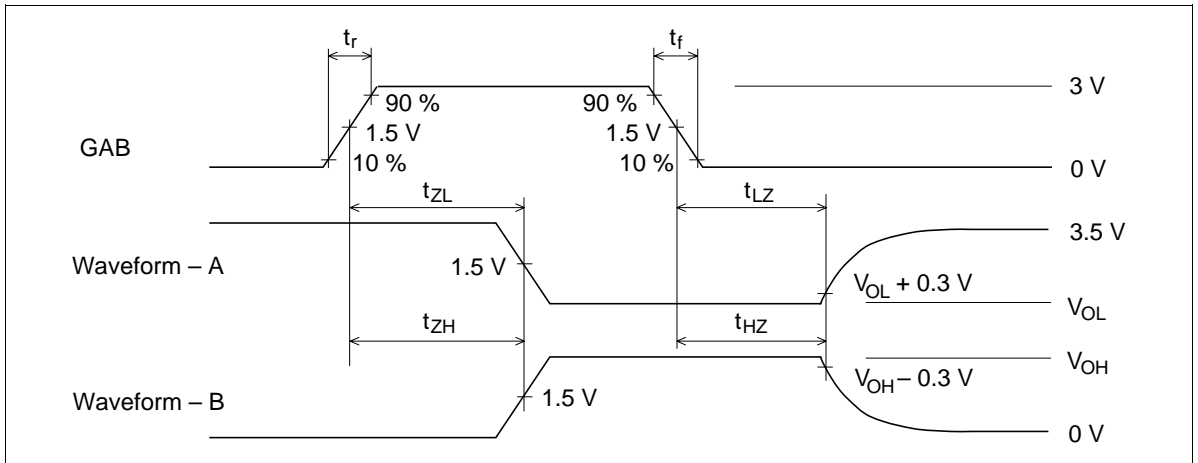


Waveforms-1

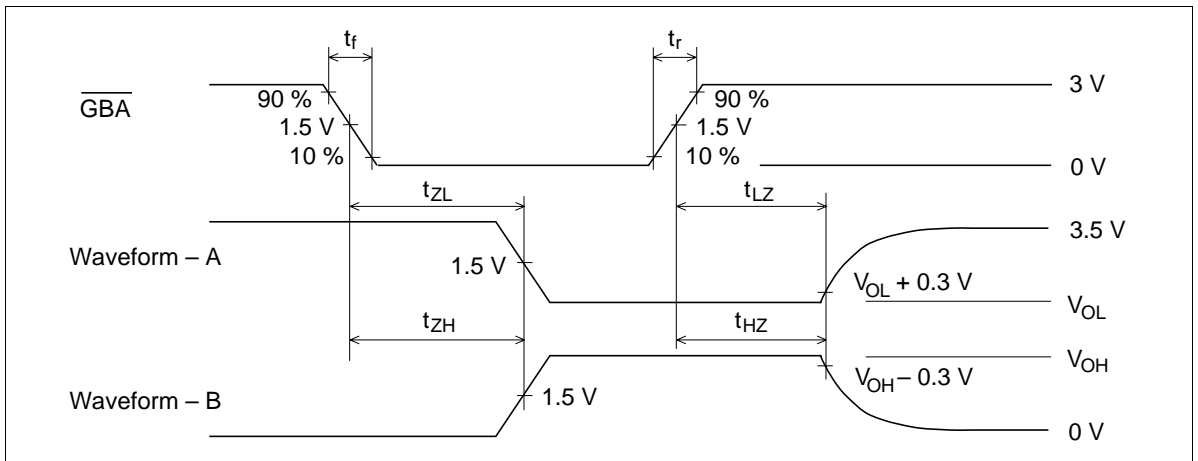


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Waveforms-2



Waveforms-3



- Notes:
1. $t_r = 2.5$ ns, $t_f = 2.5$ ns
 2. Input waveforms: PRR = 1 MHz, duty cycle 50%
 3. Waveform-A shows input conditions such that the output is “L” level when enable by the output control.
 4. Waveform-B shows input conditions such that the output is “H” level when enable by the output control.

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Package Dimensions

Unit: mm



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